

IPS021(S)

FULLY PROTECTED POWER MOSFET SWITCH

Features

- Over temperature shutdown
- Over current shutdown
- Active clamp
- Low current & logic level input
- E.S.D protection

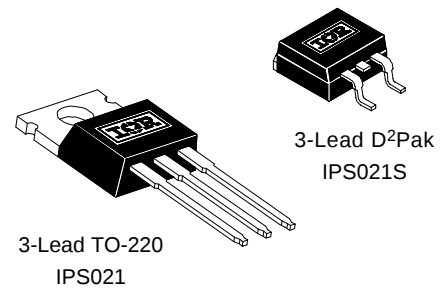
Description

The IPS021/IPS021S are fully protected three terminal SMART POWER MOSFETs that feature over-current, over-temperature, ESD protection and drain to source active clamp. These devices combine a HEXFET® POWER MOSFET and a gate driver. They offer full protection and high reliability required in harsh environments. The driver allows short switching times and provides efficient protection by turning OFF the power MOSFET when the temperature exceeds 165°C or when the drain current reaches 5A. These devices restart once the input is cycled. The avalanche capability is significantly enhanced by the active clamp and covers most inductive load demagnetizations.

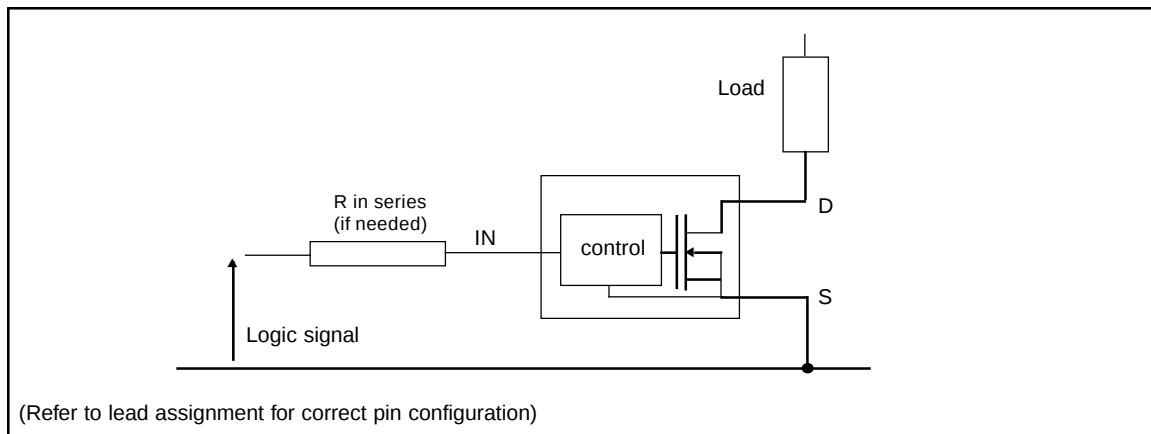
Product Summary

$R_{ds(on)}$	150m Ω (max)
V_{clamp}	50V
$I_{shutdown}$	5A
T_{on}/T_{off}	1.5 μ s

Packages



Typical Connection



IPS021(S)

International
IR Rectifier

Absolute Maximum Ratings

Absolute maximum ratings indicate sustained limits beyond which damage to the device may occur. All voltage parameters are referenced to SOURCE lead. (T_{Ambient} = 25°C unless otherwise specified). PCB mounting uses the standard foot-print with 70 µm copper thickness.

Symbol	Parameter	Min.	Max.	Units	Test Conditions
V _{ds}	Maximum drain to source voltage	—	47	V	
V _{in}	Maximum input voltage	-0.3	7		
I _{in, max}	Maximum IN current	-10	+10	mA	
I _{sd cont.}	Diode max. continuous current ⁽¹⁾			A	
	(r _{th} =62°C/W) IPS021	—	2.8		
	(r _{th} =10°C/W) IPS021	—	8		
	(r _{th} =80°C/W) IPS021S	—	2.2		
I _{sd pulsed}	Diode max. pulsed current ⁽¹⁾	—	10A		
P _d	Maximum power dissipation ⁽¹⁾			W	
	(r _{th} =62°C/W) IPS021	—	2		
	(r _{th} =80°C/W) IPS021S	—	1.56		
ESD1	Electrostatic discharge voltage (Human Body)	—	4	kV	C=100pF, R=1500Ω,
ESD2	Electrostatic discharge voltage (Machine Model)	—	0.5		C=200pF, R=0Ω, L=10µH
T _{stor.}	Max. storage temperature	-55	150	°C	
T _{j max.}	Max. junction temperature.	-40	150		
T _{lead}	Lead temperature (soldering, 10 seconds)	—	300		

Thermal Characteristics

Symbol	Parameter	Min.	Typ.	Max.	Units	Test Conditions
R _{th 1}	Thermal resistance free air	—	60	—	°C/W	TO-220
R _{th 2}	Thermal resistance junction to case	—	5	—		
R _{th 1}	Thermal resistance with standard footprint	—	80	—		D ² PAK (SMD220)
R _{th 2}	Thermal resistance with 1" square footprint	—	50	—		
R _{th 3}	Thermal resistance junction to case	—	5	—		

Recommended Operating Conditions

These values are given for a quick design. For operation outside these conditions, please consult the application notes.

Symbol	Parameter	Min.	Max.	Units
V _{ds (max)}	Continuous drain to source voltage	—	35	V
V _{IH}	High level input voltage	4	6	
V _{IL}	Low level input voltage	0	0.5	
I _{ds}	Continuous drain current (T _{Ambient} = 85°C, I _N = 5V, r _{th} = 60°C/W, T _j = 125°C)	—	1.8	A
R _{in}	Recommended resistor in series with IN pin	0.5	5	kΩ
T _{r-in (max)}	Max recommended rise time for IN signal (see fig. 2)	—	1	µS
Fr-Isc ⁽²⁾	Max. frequency in short circuit condition (V _{cc} = 14V)	0	1	kHz

(1) Limited by junction temperature (pulsed current limited also by internal wiring)

(2) Operations at higher switching frequencies is possible. See Appl. Notes.

Static Electrical Characteristics

Standard footprint 70 μm copper thickness. $T_j = 25^\circ\text{C}$ (unless otherwise specified.)

Symbol	Parameter	Min.	Typ.	Max.	Units	Test Conditions
R _{ds(on)}	ON state resistance $T_j = 25^\circ\text{C}$	100	130	150	m Ω	$V_{in} = 5\text{V}$, $I_{ds} = 1\text{A}$
	$T_j = 150^\circ\text{C}$	—	220	280		
I _{dss 1}	Drain to source leakage current	0	0.01	25	μA	$V_{cc} = 14\text{V}$, $T_j = 25^\circ\text{C}$
I _{dss 2}	Drain to source leakage current	0	0.1	50		$V_{cc} = 40\text{V}$, $T_j = 25^\circ\text{C}$
V _{clamp 1}	Drain to source clamp voltage 1	48	54	56	V	$I_d = 20\text{mA}$ (see Fig.3 & 4)
V _{clamp 2}	Drain to source clamp voltage 2	50	56	60		$I_d = I_{shutdown}$ (see Fig.3 & 4)
V _{in clamp}	IN to source clamp voltage	7	8	9.5		$I_{in} = 1\text{mA}$
V _{th}	IN threshold voltage	1	1.5	2		$I_d = 50\text{mA}$, $V_{ds} = 14\text{V}$
I _{in, -on}	ON state IN positive current	25	90	200	μA	$V_{in} = 5\text{V}$
I _{in, -off}	ON state IN positive current	50	130	250		$V_{in} = 5\text{V}$ over-current triggered

Switching Electrical Characteristics

$V_{cc} = 14\text{V}$, Resistive Load = 10Ω , $R_{input} = 50\Omega$, $100\mu\text{s}$ pulse, $T_j = 25^\circ\text{C}$, (unless otherwise specified).

Symbol	Parameter	Min.	Typ.	Max.	Units	Test Conditions
T _{on}	Turn-on delay time	0.15	0.5	1	μs	See figure 2
T _r	Rise time	0.4	0.9	2		
T _{rf}	Time to (final R _{ds(on)} 1.3)	2	6	12		
T _{off}	Turn-off delay time	0.8	2	3.5		See figure 2
T _f	Fall time	0.5	1.3	2.5		
Q _{in}	Total gate charge	—	3.3	—	nC	$V_{in} = 5\text{V}$

Protection Characteristics

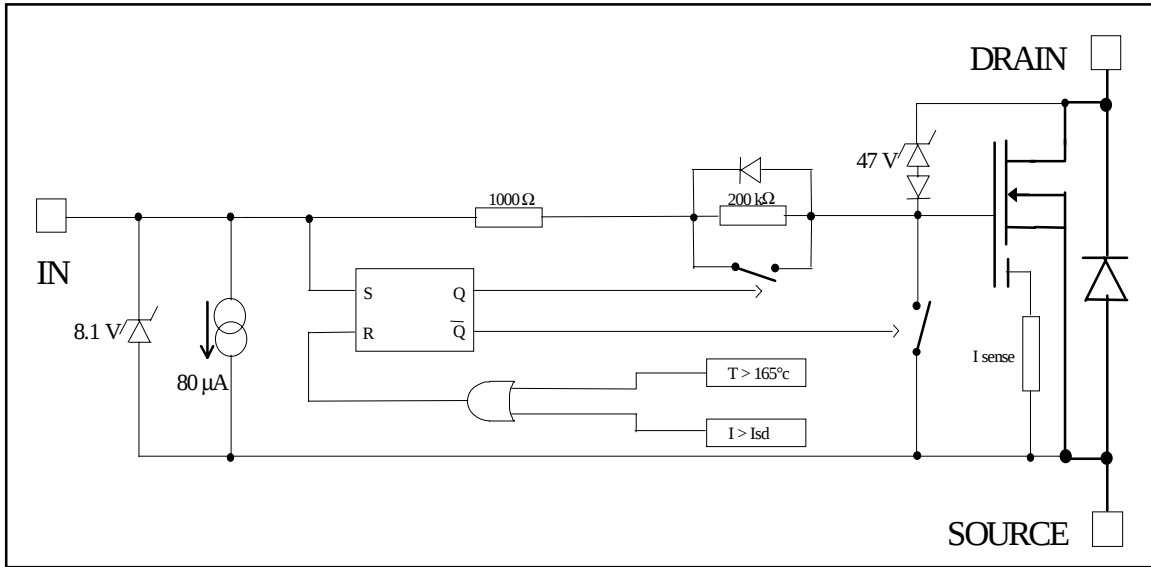
Symbol	Parameter	Min.	Typ.	Max.	Units	Test Conditions
T _{sd}	Over temperature threshold	—	165	—	$^\circ\text{C}$	See fig. 1
I _{sd}	Over current threshold	4	5.5	7	A	See fig. 1
V _{reset}	IN protection reset threshold	1.5	2.3	3	V	
T _{reset}	Time to reset protection	2	10	40	μs	$V_{in} = 0\text{V}$, $T_j = 25^\circ\text{C}$
EOI_OT	Short circuit energy (see application note)	—	400	—	μJ	$V_{cc} = 14\text{V}$

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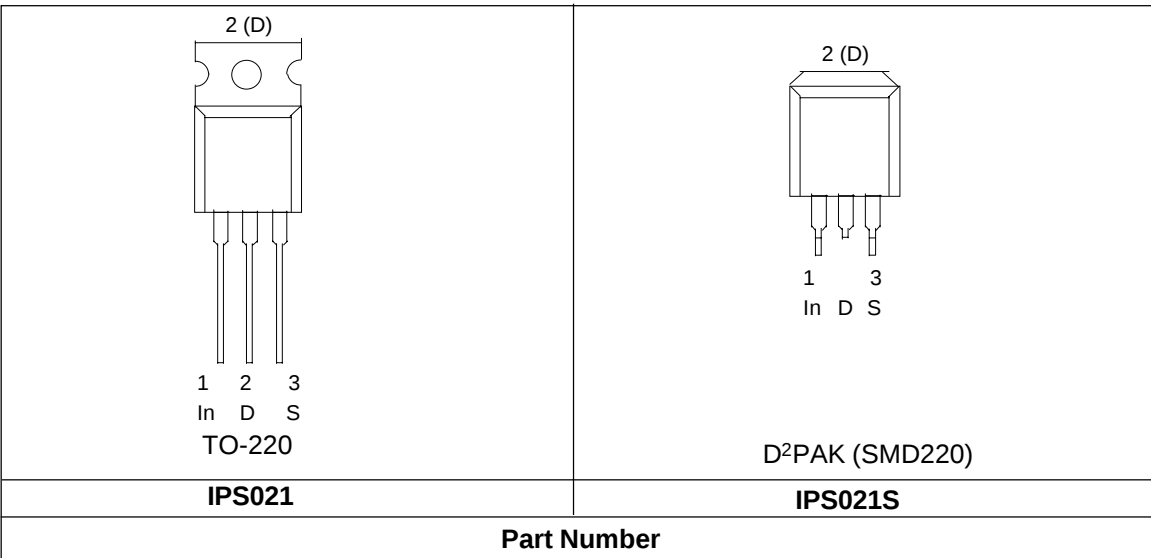
International
IOR Rectifier

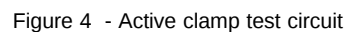
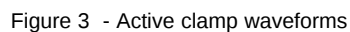
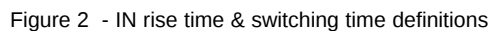
Functional Block Diagram

All values are typical



Lead Assignments





All curves are typical values with standard footprints. Operating in the shaded area is not recommended.

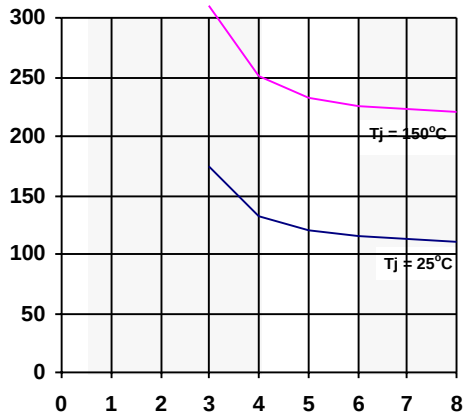


Figure 5 - Rds ON (mΩ) Vs Input Voltage (V)

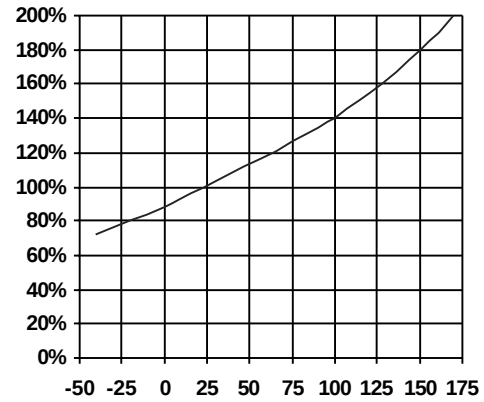


Figure 6 - Normalized Rds(on) (%) Vs Tj (°C)

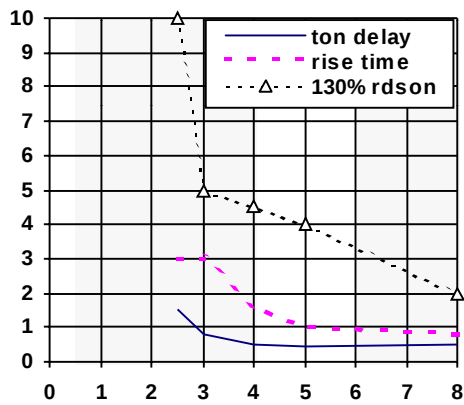


Figure 7 - Turn-ON Delay Time, Rise Time & Time to 130% final Rds(on) (us) Vs Input Voltage (V)

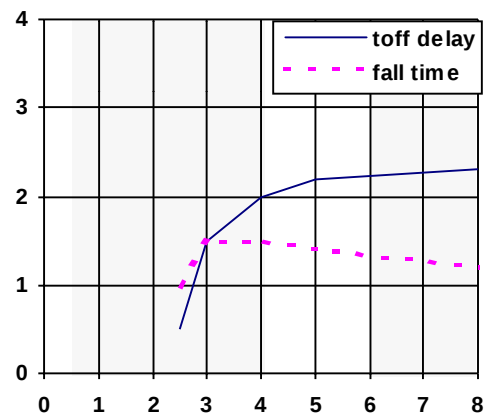


Figure 8 - Turn-OFF Delay Time & Fall Time (us) Vs Input Voltage (V)

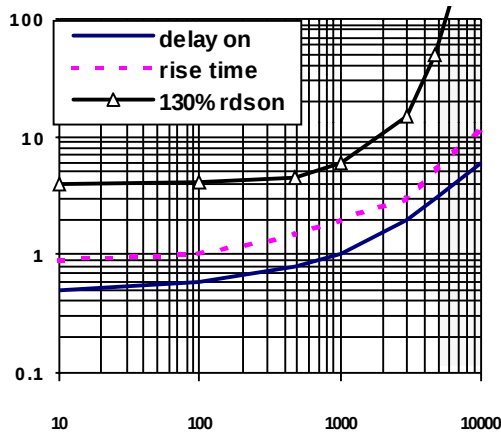


Figure 9 - Turn-ON Delay Time, Rise Time & Time to 130% final Rds(on) (us) Vs IN Resistor (Ω)

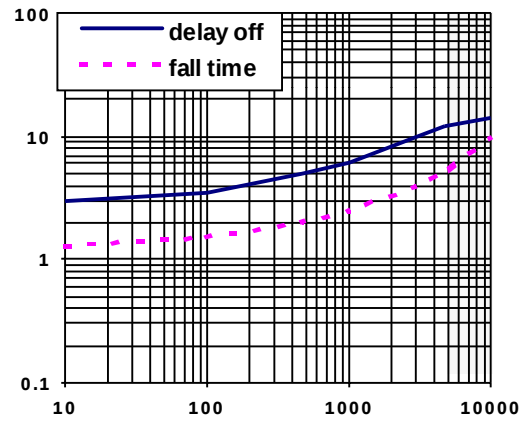


Figure 10 - Turn-OFF Delay Time & Fall Time (us) Vs IN Resistor (Ω)

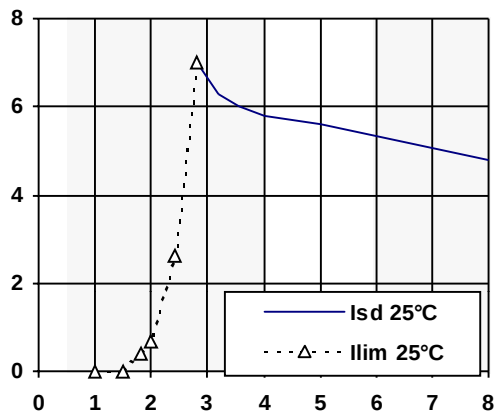


Figure 11 - Current lim. & I shutdown (A) Vs Vin (V)

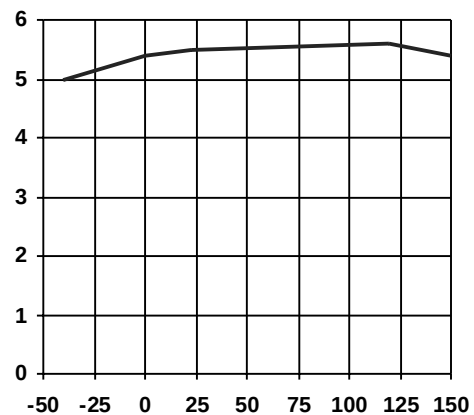


Figure 12 - I shutdown (A) Vs Temperature (°C)

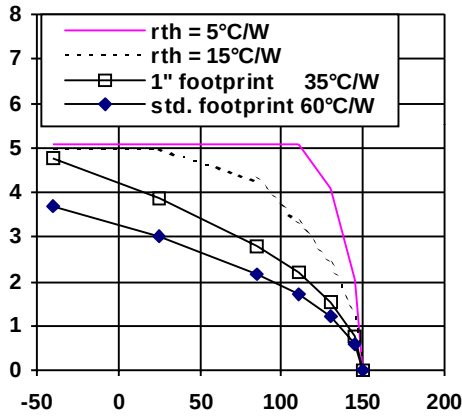


Figure 13 - Max.Cont. Ids (A)
Vs. Amb. Temperature (°C) IPS021/IPS021S

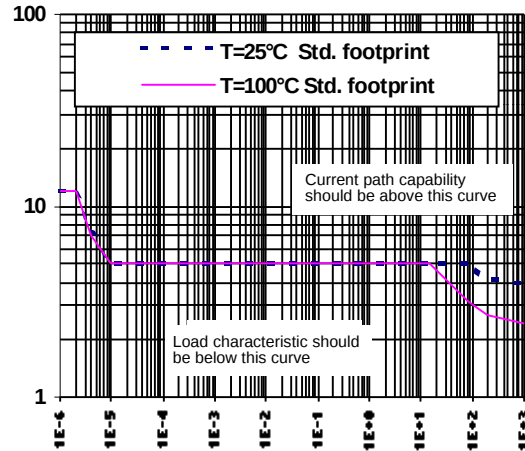


Figure 14 - Ids (A) Vs Protection Resp. Time (s)
IPS021 & IPS021S

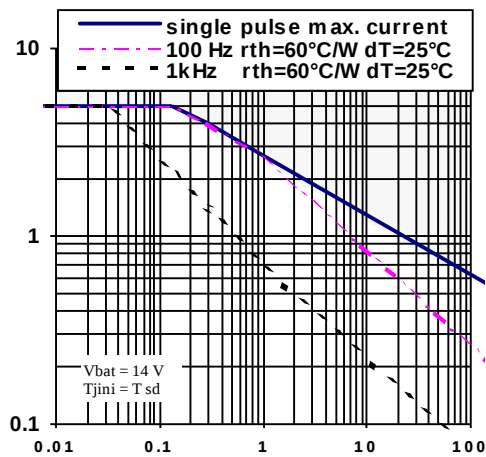


Figure 15a - Iclamp (A) Vs Inductive Load (mH)
IPS021

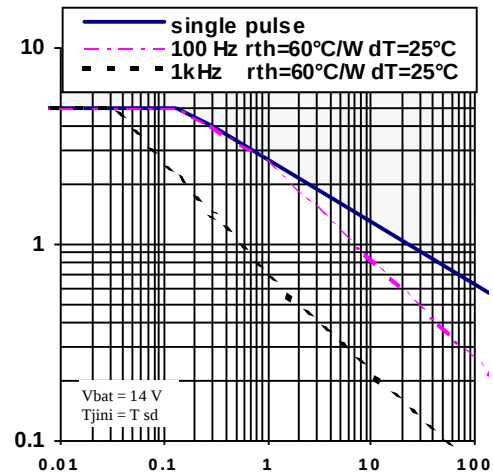


Figure 15b - Max. Iclamp (A) Vs Inductive Load
(mH) IPS021S

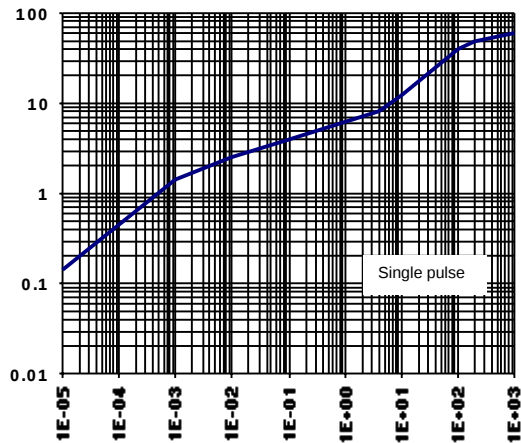


Figure 16 - Transient Thermal Imped. (°C/W)
Vs Time (s)

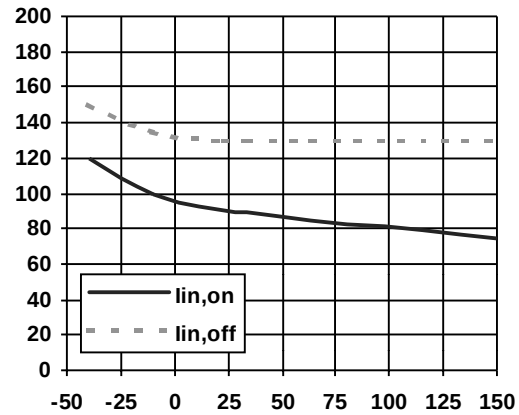


Figure 17 - Input Current (uA) Vs
Junction Temperature (°C)

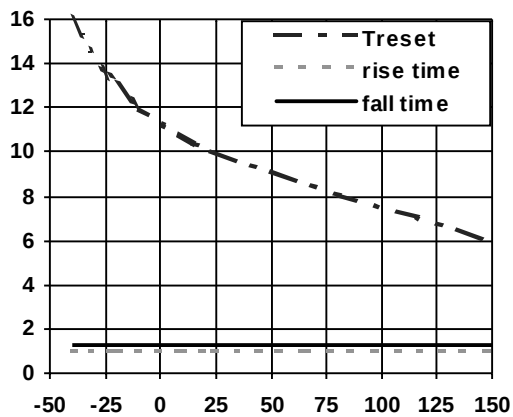


Figure 18 - Rise Time, Fall Time and Treset (μs)
Vs Tj (°C)

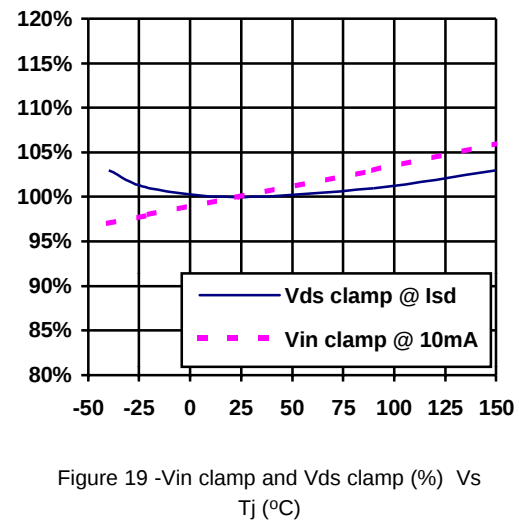
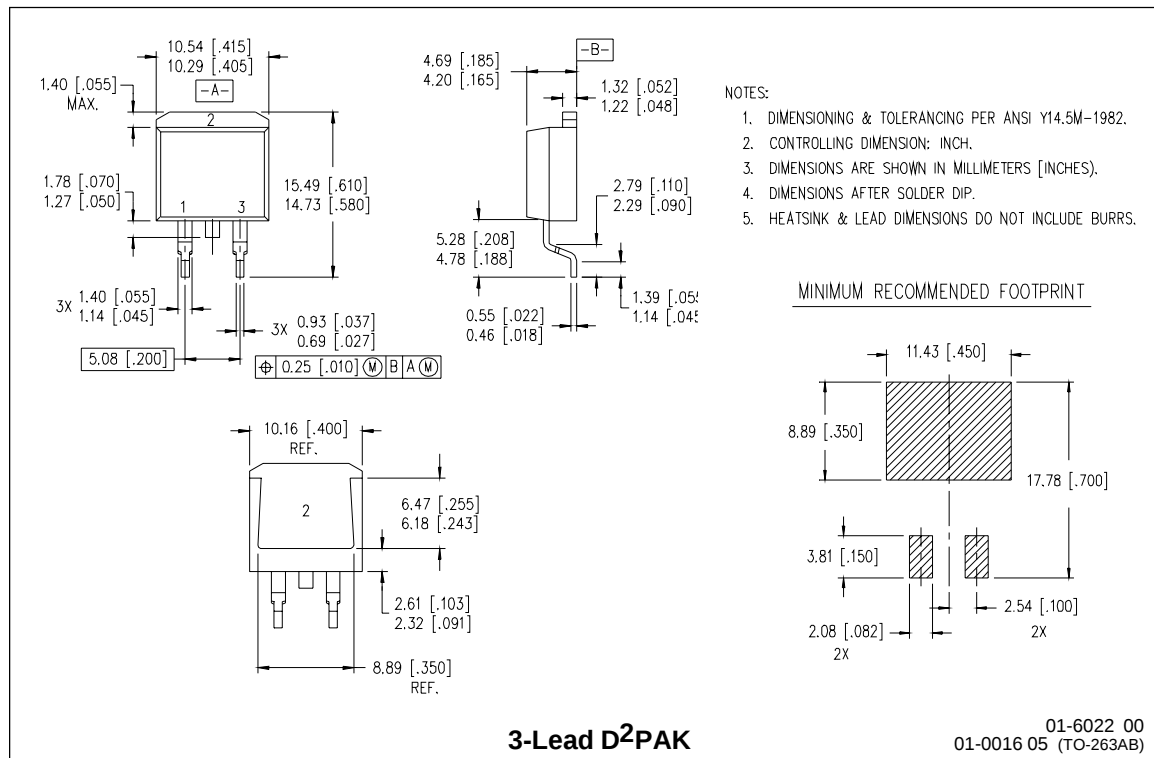
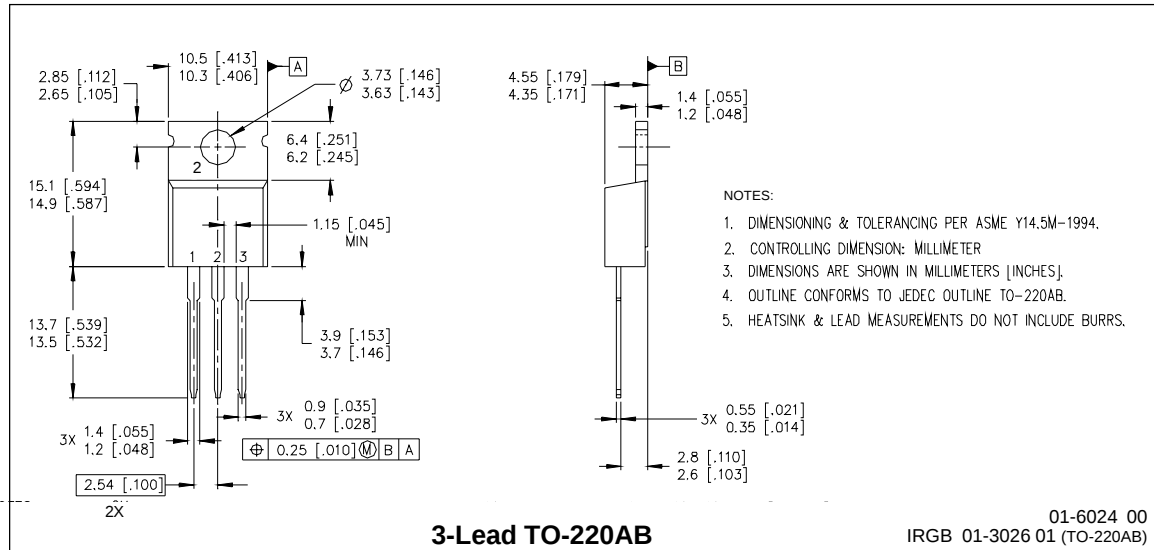


Figure 19 - Vin clamp and Vds clamp (%) Vs
Tj (°C)

Case Outline



Technical drawing of a TRR (Thermistor Resistor) component. The drawing includes a top view, a side view, and a cross-sectional view. The top view shows a circular component with three triangular segments and a central mounting point. Dimensions include a total diameter of 360.00 mm [14.173] MAX. and segment diameters of 13.52 mm [.532] and 12.80 mm [.504]. The side view shows a rectangular component with dimensions 11.60 mm [.457] and 11.40 mm [.449] for the main body, and 1.60 mm [.063] and 1.50 mm [.059] for the top flange. The cross-sectional view shows a rectangular component with dimensions 15.42 mm [.609] and 15.22 mm [.601] for the main body, and 24.30 mm [.957] and 23.90 mm [.941] for the top flange. The drawing also includes a 'FEED DIRECTION' arrow and a 'TRR' label.

NOTES:

1. OUTLINE CONFORMS TO EIA-481 & EIA-541.
2. DIMENSIONS ARE SHOWN IN MILLIMETERS [INCHES]

01-3072 00

Note: For the most current drawings please refer to the IR website at:
<http://www.irf.com/package/>

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